#### **CMDD4448**

### SURFACE MOUNT HIGH SPEED SILICON SWITCHING DIODE



SOD-323 CASE



www.centralsemi.com

# **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMDD4448 type is a ultra-high speed silicon switching diode manufactured by the epitaxial planar process, epoxy molded in a **SUPER**mini™ surface mount package, designed for high speed switching applications.

**MARKING CODE: 44** 

| MAXIMUM RATINGS: (T <sub>A</sub> =25°C)    | SYMBOL                            |             | UNITS |
|--|-----------------------------------|-------------|-------|
| Continuous Reverse Voltage                 | $V_{R}$                           | 75          | V     |
| Peak Repetitive Reverse Voltage            | V <sub>RRM</sub>                  | 100         | V     |
| Continuous Forward Current                 | I <sub>F</sub>                    | 250         | mA    |
| Peak Repetitive Forward Current            | I <sub>FRM</sub>                  | 500         | mA    |
| Peak Forward Surge Current, tp=1.0µs       | I <sub>FSM</sub>                  | 4.0         | Α     |
| Peak Forward Surge Current, tp=1.0s        | I <sub>FSM</sub>                  | 1.0         | Α     |
| Power Dissipation                          | $P_{D}$                           | 275         | mW    |
| Operating and Storage Junction Temperature | T <sub>J</sub> , T <sub>stg</sub> | -65 to +175 | °C    |
| Thermal Resistance                         | $\Theta_{JA}$                     | 545         | °C/W  |

# $\textbf{ELECTRICAL CHARACTERISTICS:} \ (T_{\mbox{\scriptsize A}} = 25^{\circ}\mbox{C unless otherwise noted})$

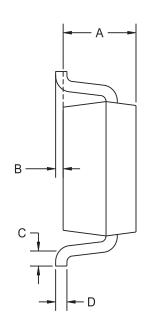
| SYMBOL          | TEST CONDITIONS   | MIN  | MAX  | UNITS |
|-----------------|---|------|------|-------|
| $I_{R}$         | V <sub>R</sub> =20V   |      | 25   | nA    |
| $BV_R$          | I <sub>R</sub> =5.0μA   | 75   |      | V     |
| $BV_R$          | I <sub>R</sub> =100μA   | 100  |      | V     |
| $V_{F}$         | I <sub>F</sub> =5.0mA   | 0.62 | 0.72 | V     |
| $V_{F}$         | I <sub>F</sub> =100mA   |      | 1.0  | V     |
| C <sub>T</sub>  | $V_R=0$ , f=1.0MHz  |      | 4.0  | pF    |
| t <sub>rr</sub> | $I_R = I_F = 10 \text{mA}$ , $R_I = 100 \Omega$ , Rec. to 1.0mA |      | 4.0  | ns    |

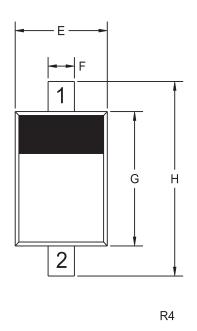
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# **SOD-323 CASE - MECHANICAL OUTLINE**





- **LEAD CODE**:
  1) CATHODE
- 2) ANODE

MARKING CODE: 44

| DIMENSIONS |   |  |   |  |  |  |  |
|------------|---|--|---|--|--|--|--|
| INCHES     |   | MILLIMETERS  |   |  |  |  |  |
| MIN        | MAX   | MIN  | MAX   |  |  |  |  |
| 0.031      | 0.039   | 0.80   | 1.00  |  |  |  |  |
| 0.000      | 0.004   | 0.00   | 0.10  |  |  |  |  |
| 0.008      | -   | 0.20   | -   |  |  |  |  |
| 0.004      | 0.007   | 0.11   | 0.19  |  |  |  |  |
| 0.045      | 0.053   | 1.15   | 1.35  |  |  |  |  |
| -          | 0.014   | -  | 0.35  |  |  |  |  |
| 0.063      | 0.071   | 1.60   | 1.80  |  |  |  |  |
| 0.094      | 0.102   | 2.40   | 2.60  |  |  |  |  |
|            | INC<br>MIN<br>0.031<br>0.000<br>0.008<br>0.004<br>0.045<br>-<br>0.063 | INCHES   MIN   MAX   0.031   0.039   0.000   0.004   0.008   - 0.004   0.007   0.045   0.053   - 0.014   0.063   0.071 | INCHES   MILLIM   MIN   MAX   MIN   0.031   0.039   0.80   0.000   0.004   0.00   0.008   - 0.20   0.004   0.007   0.11   0.045   0.053   1.15   - 0.014   - 0.063   0.071   1.60 |  |  |  |  |

SOD-323 (REV: R4)

R6 (8-January 2010)